INTEGRATED CIRCUIT **TOSHIBA** TECHNICAL DATA

TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT TA8132AN, TA8132AF

SILICON MONOLITHIC

3V AM / FM IF + MPX (for Digital Tuning System)

TA8132AN, TA8132AF are the AM/FM IF+MPX system ICs, which are designed for DTS Radios.

These are included many functions and these can be used for Digital Tuning System with IF Counter.

FEATURES

- Built-in AM/FM IF and FM Stereo PLL Multiplex Decoder.
- Suitable for combination with Digital Tuning System which is included IF Counter.
 - One terminal type AM/FM IF Count Output (Auto Stop Signal) for IF Counter of Digital Tuning System.

FM: 10.7MHz changeable by

1.3375MHz (1/8 dividing) external switch

AM: 450kHz

O Built-in Mute Circuit for IF Count Output.

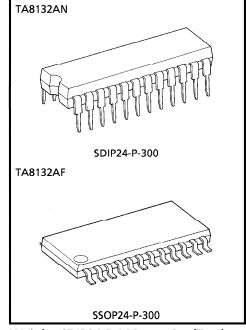
It is controlled by the IF Request Signal from Digital Tuning System,

Pin® level: High→Come out

Low →Non output

- Adjustable for IF Count Output Sensitivity by External Resistance of pin②.
- For adopting Ceramic Discriminator and Ceramic Resonator, it is not necessary to adjust the FM Quad Detector Circuit and MPX VCO Circuit.
- Built-in One terminal type AM Low Cut Circuit.
- Operating Supply Voltage Range (Ta = 25°C)

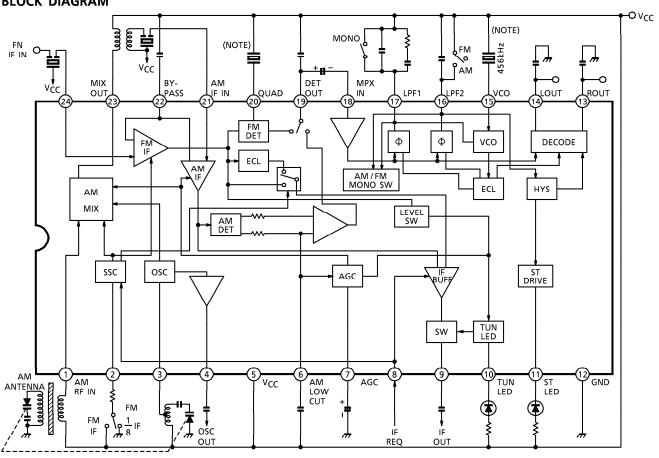
$$V_{CC(opr.)} = 1.8V \sim 8.0V$$



Weight SDIP24-P-300 : 1.2g (Typ.) SSOP24-P-300 : 0.31g (Typ.)

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BLOCK DIAGRAM



(NOTE)

We recommend

Ceramic resonator : CSB456F18

Ceramic discriminator: CDA10.7MG18 (MURATA MFG CO., LTD)

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EXPLANATION OF TERMINALS

PIN No.	ITEM	INTERNAL CIRCUIT	DC VOLT (at no AM	TAGE (V) signal) FM
1	AM RF IN	V _{CC} (S)	3.0	3.0
2	 IF Count Output Sensitivity Adjust Terminal FM IF Divider Control Terminal 	VCC (3)	_	_
3	AM OSC	VCC S BUFF AMP ALC	3.0	3.0
4	AM OSC OUT	VCC S AM OSC 4 GND 12	2.7	3.0
5	V _{CC}	_	3.0	3.0
6	AM LOW CUT	VCC (5) 122kΩ 132kΩ 132k	2.3	2.3

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PIN No.	ITEM	INTERNAL CIRCUIT DC VOLTAGE (at no sign		TAGE (V) signal)
INO.			AM	FM
7	AGC	VCC 5 GND 12 SEARCH MODE : HIGH	0.25	0.35
8	IF OUT SW	8-w-1 12	_	_
9	IF OUT	VCC (5) (1) (1) (1) (1) (1) (1) (1) (1) (1) (1	3.0	3.0
10	TUN LED (Tuning LED)	VCC (5) (10) (10) (10) (10) (10) (10) (10) (10	_	_
11	ST LED (Stereo LED)	19kHz		_
12	GND	_	0	0
13 14	R-OUT L-OUT	V _{CC} (5)	1.0	1.0

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PIN No.	ITEM	INTERNAL CIRCUIT	DC VOL [*] (at no AM	TAGE (V) signal) FM
15	vco	V _{CC} (3) (13) (13) (14) (14) (14) (14) (14) (14) (14) (14	2.5	2.5 (VCO Stop mode)
16	LPF2 • LPF Terminal for Synchronous Detector • Bias Terminal for AM / FM Switch Circuit V16 = VCC → AM V16 = open→FM	GND 12	3.0	2.2
17	LPF1 ■ LPF Terminal for Phase Detector ■ VCO Stop Terminal V ₁₇ = V _{CC} →VCO Stop	GND 12	2.7	2.2
18	MPX IN	(18) W W W W W W W W W W W W W W W W W W W	0.7	0.7
19	DET OUT	VCC 3 AM FM GND (12)	1.1	1.1

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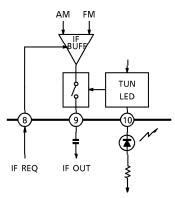
PIN No.	ITEM	INTERNAL CIRCUIT	DC VOLT	TAGE (V) signal)
110.			AM	FM
20	QUAD (FM QUAD. Detector)	VCC (3)	2.4	2.1
21	AM IF IN	Vcc (5) G (2) (2) (1) (1) (1) (1) (1) (1) (1) (1) (1) (1	3.0	3.0
22	BY-PASS (AM IF AMP BY-PASS) FM IF AMP	GND (12)	2.3	2.8
23	AM MIX OUT	VCC (S) MIX GND (12)	3.0	3.0
24	FM IF IN	VCC (S) BY-PASS (22) GND (12)	3.0	3.0

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APPLICATION NOTE

1. How to control the IF Count Output Signal (pin 9 output)



	TUN LED		LED
		ON OFF	
1/2	Н	Come out	Non output
_ v8	L	Non output	Non output

Whether or not there is the IF Count output signal (pin® output) is determined by the AND of the pin® control voltage: V₈ and tuning LED on/off switching.

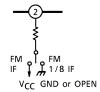
In the condition of

 V_8 : High (Active High, $V_{TH} = 0.8V$ (Typ.))

TUN LED : ON $(V_{in} \ge V_L + 2dB\mu V EMF (Typ.))$

the IF count output signal comes out from the pin[®]. In the case of the Tuning LED function is not needed, it doesn't matter the pin[®] is opened.

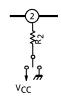
- \odot The output impedance of pin $\$ is 1.5k $\$ (Typ.) (cf. P.4) It is possible to reduce the IF count output signal level to add the resistance between the pin $\$ and the V_{CC} line.
- \circ The signal waveform is the rectangular wave, and the level is 500mV_{p-p} (Typ.)
- 2. How to control the Divider of FM IF



Switch

VCC : 10.7MHz output GND or Open : 1.3375MHz output (1/8 dividing)

- 3. How to adjust the IF Count Output Sensitivity
 - The IF Count Output Sensitivity (Search sensitivity)
 Can be adjusted by varying the IF AMP gain for FM and varying the Mixer gain for AM. This setting is made by changing the value of external resistance R₂ which is connected to pin②.

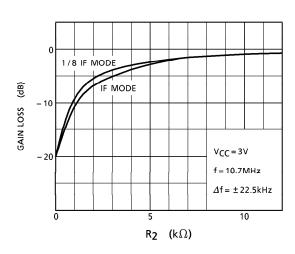


O However, this is only possible at the Auto-Tuning Mode. (external voltage supplied to pin® is at High level.) The original again returns while receiving a broadcast station (supplied voltage to pin® is at Low level.)

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○ The Gain Loss of FM IF AMP

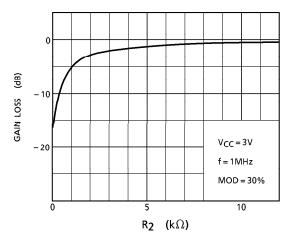
		R ₂			
		Ω 0	10k Ω (Note)		
MODE	IF (10.7MHz)	– 20dB	– 1dB		
MC	1/8 IF (1.3375MHz)	– 20dB	– 1dB		



(Note)

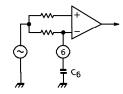
- In the condition of the 1/8 IF Mode, it is possible to set up R₂ = ∞ (open).
- In the condition of IF Mode, it is necessary to set up the value of R_2 under $10k\Omega$. When the R_2 is over $10k\Omega$ it is feared that the Mode is change to the 1/8 IF Mode.
- The Gain Loss of AM Mixer

R	2
Ω 0	10k Ω
– 16dB	– 1dB



4. AM Low-Cut Circuit

 The AM Low-Cut action is carried out by the bypass of the high frequency component of the positive-feedback signal at the AF AMP stage. The external capacitor: C₆ by-passes this component.



 \odot The cut-off frequency fL is determine by the internal resistance 22k Ω (Typ.) and the external capacitor C6 as following ;

$$f_L = \frac{1}{2 \times \pi \times 22 \times 10^3 \times C_6} (Hz)$$

○ In the case of the AM Low-Cut function is not needed, set up the value of C₆ over 0.47μ F. In the condition of C₆ \geq 0.47μ F, the frequency characteristic has flat response at the low frequency.

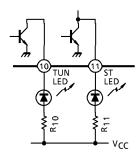
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5. AM Local Oscillator Buffer Output

- \odot The output impedance of AM Local Oscillator Buffer Output pin (Pin4) is 750 Ω (Typ.) (cf. P.3)
- It is possible to reduce the output level to add the resistance between the pin@ and V_{CC} line. The signal waveform is the rectangular wave, and the level is 500mV_{p-p} (f_{OSC} = 1.45MHz, Typ.)
- The higher local oscillation frequency (f_{OSC}) to be, the lower buff output level to be owing to the load capacity. So, in the case that it is connected to other circuits, take care of the input capacity of these circuits and stray capacity of wire.

6. Tuning LED Driver and Stereo LED Driver

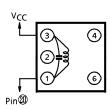
- The Tuning LED Driver and Stereo LED Driver don't have current limit resistance shown in the right figure. So, it is necessary to add the current limit resistance: R₁₀, R₁₁.
- Set up the values of R₁₀, R₁₁ to keep the drive currents ID10, ID11 under 10mA.



7. FM Detection Circuit

For the FM detection circuit, detection coil is able to use instead of ceramic discriminator. Recommended circuit and recommended coil are as follows. In this case, please take care that V_{in} (lim.) falls a little.





TEST	Co	Co			TUF	RNS		WIRE	REF
FREQUENCY	(pF)	Q°	1-2	2-3	1-3	4-6	$(mm\phi)$	KEF	
10.7MHz	100	100			12		0.12 UEW	SUMIDA ELECTRIC CO., LTD	
10.7101712	0	100			12		U. IZ UEVV	2153-4095-189 or Equivalent	

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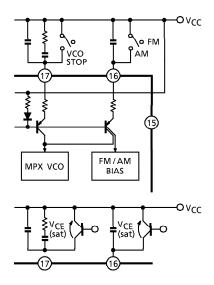
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8. FM/AM Switch and Forced Monaural Switch

FM/AM switch over and stere/forced monaural switch over are done by internal PNP transistors ON/OFF which are connected to pin® and pin® respectively.

The threshold voltages of these PNP transistors are $V_{th} = V_{CC}$, and for switching, we recommend to use mechanical switch. (Direct short to V_{CC} line.)

In the case of the electrical switch over by transistor, set up V_{CE} (saturation voltage between collector and emitter) 50mV or less, otherwise there are some cases that it does not become the AM mode and force monaural mode. When these external switches are ON, the currents which flow into pin® and pin® are 100μ A and 20μ A respectively. (Typical value at V_{CC} = 3V)



MAXIMUM RATINGS (Ta = 25°C)

CHARACTER	RISTIC	SYMBOL	RATING	UNIT	
Supply Voltage		VCC	8	V	
LED Current		lLED	10	mA	
LED Voltage		V_{LED}	8	V	
Power Dissipation	TA8132AN	D- (Noto)	1200	mW	
Power Dissipation	TA8132AF	P _D (Note)	400		
Operating Temper	ature	T _{opr}	– 25∼75	°C	
Storage Temperati	ıre	T_{stg}	- 55∼150	°C	

Note: Derated above 25°C in the proportion of 9.6mW/°C for TA8132AN and of 3.2mW/°C for TA8132AF.

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ELECTRICAL CHARACTERISTICS

Unless otherwise specified, Ta = 25°C, V_{CC1} = 3V, $SW_1 \rightarrow 10k\Omega$, $SW_3 \rightarrow OFF$

FM IF : f = 10.7 MHz, $\Delta f = \pm 22.5 \text{kHz}$, $f_m = 1 \text{kHz}$ AM : f = 1 MHz, MOD = 30%, $f_m = 1 \text{kHz}$ MPX : $f_m = 1 \text{kHz}$

			****** * *						
CHARACTERISTIC			SYMBOL	TEST CIR- CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Supply Current			I _{CC} (FM)	1	FM Mode, V _{in} = 0	 	11.0	14.0	mA
Suppi	y Current		I _{CC} (AM)	1	AM Mode, V _{in} = 0	<u> </u>	10.5	13.5	MA
	Input Limitin Voltage	g	Vin (lim.)	1	-3dB Limiting Point	41	46	51	dBμV EMF
	Recovered O Voltage	utput	V _{OD}	1	V _{in} = 80dBμV EMF	50	75	100	mV _{rms}
	Signal to No Ratio	ise	S/N	1	V _{in} = 80dBμV EMF	_	65	_	dB
	Total Harmonic Distortion		THD	1	$V_{in} = 80 dB \mu V EMF$	_	0.2	_	%
	AM Rejection	n Ratio	AMR	1	$V_{in} = 80 dB \mu V EMF$		38	_	dB
	LED ON Sensitivity		VL	1	I _L = 1mA	48	53	58	dBμV EMF
FM	IF Count Output Frequency	IF	f _{IF} (FM)	1	$V_{in} = 80 \text{dB} \mu \text{V EMF,}$ $SW_2 \rightarrow V_{CC}$, $SW_3 \rightarrow ON$	_	10.7	_	NALL-
IF		1/8 IF	f _{1/8 IF} (FM)	1	$V_{in} = 80 \text{dB} \mu \text{V EMF},$ $SW_2 \rightarrow GND, SW_3 \rightarrow ON$	1.3374	1.3375	1.3376	MHz
	IF Count Output	IF	V _{IF} (FM)	1	$V_{in} = 61 dB \mu V EMF,$ $SW_2 \rightarrow V_{CC}, SW_3 \rightarrow ON$	350	500	_	m\/
	Voltage	1/8 IF	V _{1/8 IF} (FM)	1	$V_{in} = 61 dB \mu V EMF,$ $SW_2 \rightarrow GND, SW_3 \rightarrow ON$	350	500		mV _{p-p}
					SW ₁ →0, SW ₂ →GND, SW ₃ →ON	_	76	_	
	IF Count Out	IF Count Output			$SW_1 \rightarrow 510\Omega$, $SW_2 \rightarrow GND$, $SW_3 \rightarrow ON$		68	_	$dB\muV$
	Sensitivity		IF _{sens.} (FM)	1	SW ₁ →0, SW ₂ →V _{CC} , SW ₃ →ON	_	77	_	EMF
					$SW_1 \rightarrow 510\Omega$, $SW_2 \rightarrow V_{CC}$, $SW_3 \rightarrow ON$	_	69	_	

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	CHARACTERISTIC	SYMBOL	TEST CIR- CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
	Gain	GV	1	$V_{in} = 26dB\mu V EMF$	28	57	85	
	Recovered Output Voltage		1	V _{in} = 60dBμV EMF	50	75	100	mV _{rms}
	Signal to Noise Ratio	S/N	1	$V_{in} = 60 dB \mu V EMF$	_	41	_	dB
	Total Harmonic Distortion	THD	1	V _{in} = 60dBμV EMF	_	1.0	_	%
AM	LED ON Sensitivity	VL	1	I _L = 1mA	21	26	31	dBμV EMF
	Local OSC Buff.	V _{OSC} (AM)	1	f _{OSC} = 1.45MHz	350	500	—	mV _{p-p}
	Output Voltage		2	f _{OSC} = 27MHz	_	500	_	ш Ф-р
	IF Count Output Voltage		1	$V_{in} = 39 dB \mu V EMF, SW_3 \rightarrow ON$	350	500	_	mV _{p-p}
	IF Count Output Sensitivity	IF _{sens.} (AM)	1	SW ₁ →0, SW ₂ →GND, SW ₃ →ON	_	49	_	
				SW ₁ →510 Ω , SW ₂ →GND, SW ₃ →ON		42	_	$dB\muV$
				SW ₁ →0, SW ₂ →V _{CC} , SW ₃ →ON	_	49	_	EMF
				$SW_1 \rightarrow 510\Omega$, $SW_2 \rightarrow V_{CC}$, $SW_3 \rightarrow ON$		42		
Din(10)	Output Resistance	Pag	1	FM Mode	_	0.6	_	k Ω
	Output Resistance	R ₁₉	<u> </u>	AM Mode		12		K77

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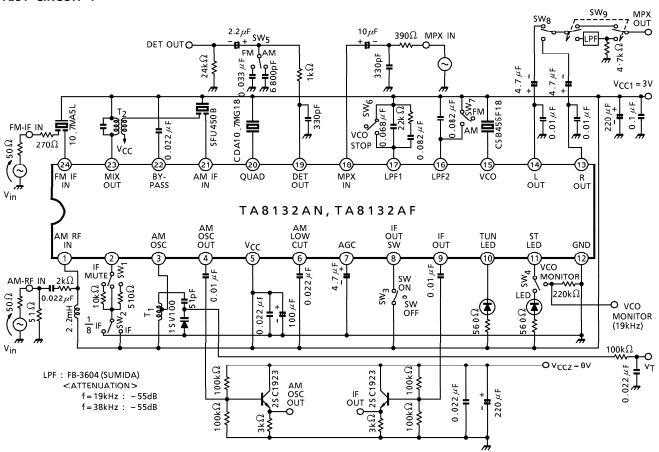
CHARACTERISTIC		SYMBOL	TEST CIR- CUIT	TEST CONDITION		MIN.	TYP.	MAX.	UNIT	
	Input Resist	ance	R _{IN}	1	_		_	25	_	kΩ
	Output Res	istance	ROUT	1	_		_	5	_	K77
	Max. Comp Signal Inpu		V _{in} MAX (Stereo)	1	L + R = 90%, P = 10% THD = 3%, SWg→LPF : ON		_	350	_	mV _{rms}
					$L + R = 135 \text{mV}_{rms}$	f _m = 100Hz	_	42	_	
	Separation		Sep	—		f _m = 1kHz	35	42	_	dB
						f _m = 10kHz	_	42	_	1
	Total Harmonic Distortion	Monaural	THD (Monaural)		$V_{in} = 150 \text{mV}_{rms} \text{ (MONO)}$		_	0.2	_	
МРХ		Stereo	THD (Stereo)	1	L+R=135mV _{rms} , P=15mV _{rms} SWg \rightarrow LPF: ON		_	0.2	_	%
	Voltage Gain		G _V (MPX)	1	$V_{in} = 150 \text{mV}_{rms}$ (F	MONO)	- 5	- 3	- 1	dB
	Channel Ba	lance	C.B.	1	$V_{in} = 150 \text{mV}_{rms}$ (N	V _{in} = 150mV _{rms} (MONO)		0	2	dB
	Stereo LED	ON	V _L (ON)	1	Pilot Input		_	8	15	
	Sensitivity	OFF	V _L (OFF)	L'			2	6	_	m∨rms
	Stereo LED Hysteresis		VH	1	To LED turn off from LED turn on		_	2		mV _{rms}
	Capture Range		C.R.	1	P = 15mV _{rms}		_	± 1.3	_	%
	Signal to Noise Ratio		S/N	1	V _{in} = 150mV _{rms} (MONO)		_	78	_	dB

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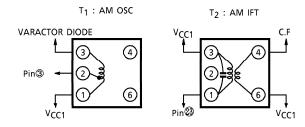
TEST CIRCUIT 1



COIL DATA (TEST CIRCUIT 1)

COIL No.	r L	L	Co		TURN				WIRE	RED. (COIL No.)
COIL NO.		(μH)	(pF)	Ųο	1-2	2-3	1-3	4-6	(mm)	KED. (COIL NO.)
T ₁ AM OSC	796kHz	288	_	115	13	73	_	_	0.08 UEW	4147-1356-038 🛇
T ₂ AM IFT	455kHz	_	180	120	_	_	180	15	0.06 UEW	2150-2162-165 S

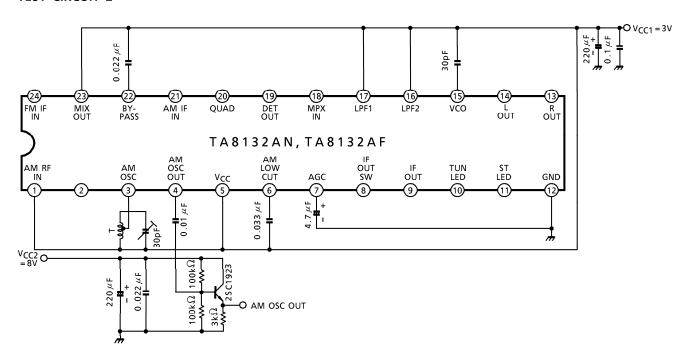
S: SUMIDA ELECTRIC Co., Ltd.



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TEST CIRCUIT 2

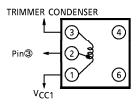


COIL DATA (TEST CIRCUIT 2)

COIL No.	COULNO f L CO		C_O	0	TURN				WIRE	REF. (COIL No.)
COIL NO.	•	(μH)	(pF)	ŷ	1-2	2-3	1-3	4-6	(mm)	KEF. (COIL NO.)
T AM OSC	7.96MHz	1.4	_	84	1	6	7		0.08 UEW	① 7PL-1344Y

①: TOKO Co., Ltd.

T: AM OSC

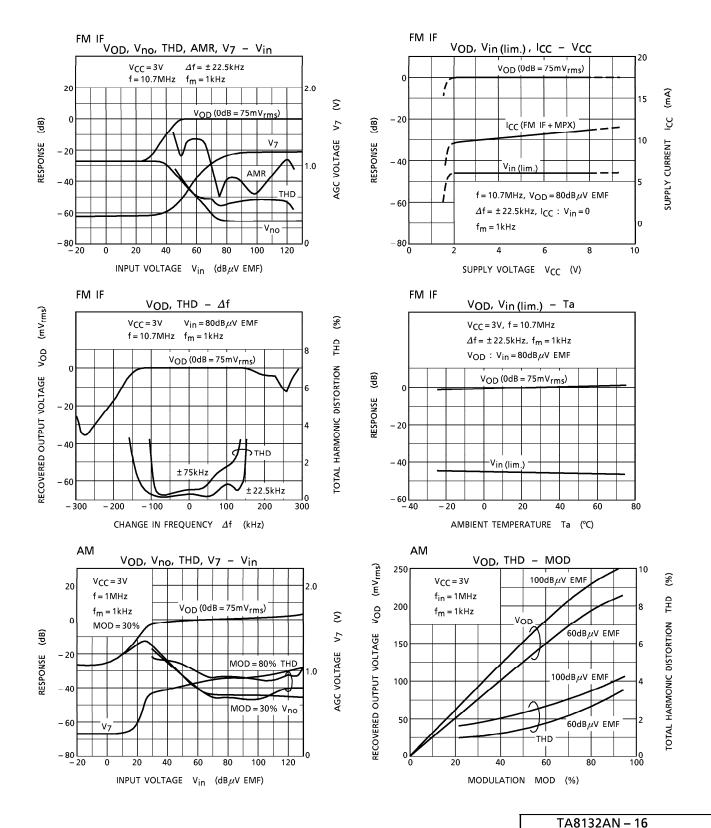


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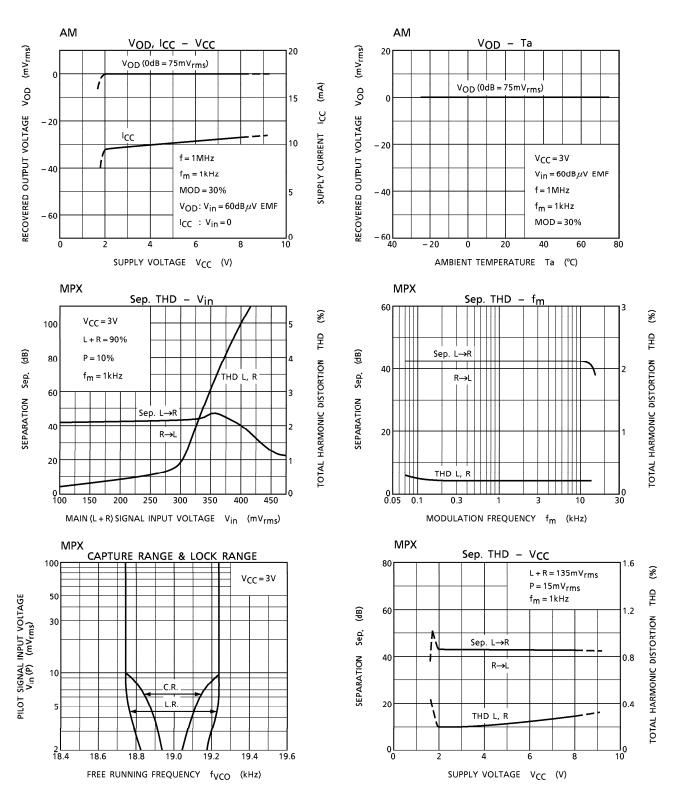
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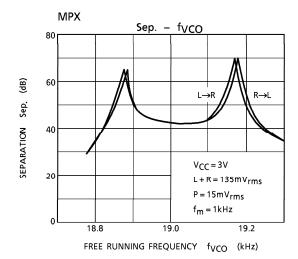
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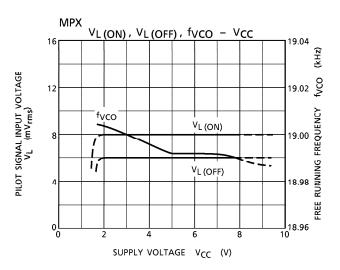
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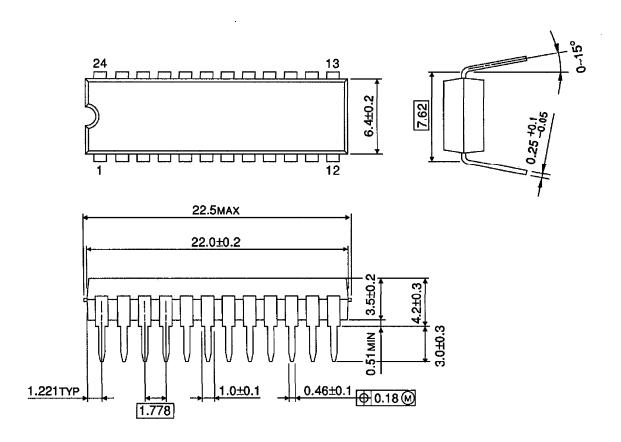
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Unit: mm



Weight: 1.2g (Typ.)

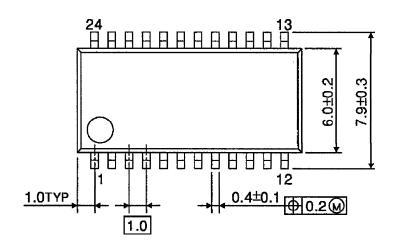
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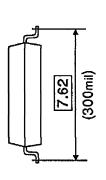
TECHNICAL DATA

TA8132AN, TA8132AF

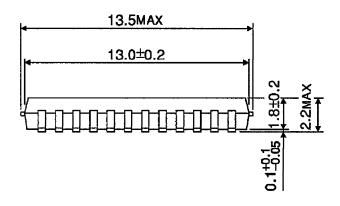


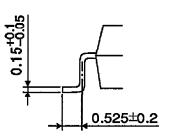
SSOP24-P-300





Unit: mm





Weight: 0.31g (Typ.)

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